Switchable bandstop to allpass filter using cascaded transmission line SIW resonators in K-band

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ABSTRACT

In this paper, a switchable bandstop to allpass filter using cascaded transmission line SIW resonators is proposed. The switchable filter is performed by the switchable cascaded transmission line SIW resonators using discrete PIN diodes. Therefore, it can be used for rejecting any unwanted frequencies in the communication systems. The proposed filter design is operated in K-band and targeted for millimeter wave front end system for 5G telecommunication. Two filter designs with different orientation (design A and B) are investigated for the best performance and compact size. As a result, design B is the best by giving a maximum attenuation of 39.5 dB at 26.4 GHz with the layout size of 33×30 mm.

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1. INTRODUCTION

As modern wireless and microwave systems have advanced towards a spectral cognitive system, there will be a need for further filter reconfiguration to allow the full potential of this system performance such as 5G technology [1]-[3]. Reconfigurable filters including switchable and tunable filters have been of great interest because they were designed to be versatile wireless systems that capable of occupying different bandwidths, responses, and frequencies [4]-[10]. Therefore, RF front ends that need to accommodate changes in the spectrum and provide adaptive filtering can include a switchable, reconfigurable and tunable filters. One of the designs is focusing on the switchable bandstop to allpass filters [11]-[15], where it can be used for rejecting any unwanted frequencies in the communication systems. Besides, some traditional filter banks take much space to the circuit board which not suitable for integration and low-cost mass production [16] and therefore, most of the reconfigurable filter designs are using varactor diodes, PIN diodes or micro electromechanical systems (MEMs). Thus make it compact in size compared to the traditional filter banks.

On the other hand, substrate integrated waveguide (SIW) is found to be a suitable choice in microwave and millimeter wave for designing and developing the components such as antenna [17], filter [18] and power divider [19]. As reported in [16], there are advantages of SIW over the conventional metallic waveguides such as low loss and high-quality factor for SIW cavities, permanent electrical isolation due to the shielding via posts, high power handling and the integrability capabilities of SIW structures with all sorts of passive and active components. As reported by previous researchers in [20]-[23], most of the reconfigurable filter designs using SIW are either for bandstop filter or bandpass filter.

Therefore, this paper proposes a switchable bandstop to allpass filter using cascaded transmission line SIW resonator. The switchable filter is performed by the switchable cascaded transmission line SIW resonators using discrete PIN diodes. The design consists of four cascaded SIW resonators and it is operated in K-band. The proposed filter is targeted for millimeter wave front end system for 5G telecommunication. Two filter designs with different orientation (design A and B) are investigated for the best performance and compact size. Beside that, in this paper, a tapered microstrip transition and rectangle microstrip transition are investigated for the best performance in this filter design.

2. CIRCUIT DESIGN OF SWITCHABLE BANDSTOP TO ALLPASS FILTER

2.1. Switchable transmission line siw resonator

The switching element of the SIW resonator in Figure 1 is performed by using a discrete PIN diode to allow the switching between bandstop and allpass responses. The bandstop of the resonator is operated due to the resonant frequency of a quarter wavelength ($\lambda/4$) of the open stub of the SIW transmission line. The PIN diode is operated by two different states which are ON state and OFF state. For OFF state and ON state of the PIN diode, the voltage supplies are +5 V and -5 V respectively. The resonator's switchable operation is explained as follows. The PIN diode of the SIW resonator is supplied with +5 V (OFF state), which allows allpass response and is supplied with -5 V (ON state) for switching to a bandstop response. In the SIW structure, via holes form a major part of the SIW to realize the bilateral edge walls. Via holes are the most important discontinuities in multilayered circuits. Therefore, in designing via holes of the SIW, the following in [24] and [25] are used,

$$\lambda_g = \frac{2\pi}{\sqrt{\frac{\epsilon_r(2\pi f)^2}{2} - \frac{\pi}{C}^2}}$$
(1)

$$d < \frac{\lambda_g}{5} \tag{2}$$

$$p \le 2d \tag{3}$$

Where λ_g is the guided wavelength, *d* is the diameter of the via and *p* is the pitch between the via. Take note that, (2) and (3) are used to ensure that the radiation leakage will be maintained at a very low amount and with that, SIW can be designed almost similar to the conventional rectangular waveguide with the appropriate dimension of *d* and *p*.



Figure 1. Switchable transmission line SIW resonator

2.2. SIW Resonator with microstrip transition

In order to combine the SIW and microstrip transmission lines, SIW to microstrip transitions are required [26]-[29]. The design of this transition is very critical and important to achieve a good performance of the filter design. In order to fine the best transition, this paper investigates the tapered microstrip transition and rectangle microstrip transition. Therefore, (4) is used to determine the width of the transition [30]:

$$Z_1 = Z_0 Z_2 \tag{4}$$

By using (4), we can design the microstrip transition accordingly as shown in Figure 2 (a) and 2 (b). Both circuit designs consist of tapered and rectangle microstrip lines section that connected to 50 Ω impedance of microstrip line and SIW resonator.



Figure 2. Switchable SIW resonator with; (a) tapered microstrip transition, (b) rectangle microstrip transition

2.3. Cascaded switchable transmission line SIW resonators

Two circuits of bandstop to allpass reconfigurable filter with four cascaded switchable SIW resonators (S1, S2, S3 and S4) are illustrated in Figure 3 (a) and 3 (b) for design A and B respectively. The proposed filter circuits were constructed in CST software. All the Roger RT/duroid 5880 substrate parameters such as thickness of 0.254 mm and relative dielectric constant of 2.2 were included in the filter design. The proposed design was simulated with ideal PIN diodes which are open circuited for OFF state and short circuited for ON state.



Figure 3. Switchable bandstop to allpass filter of, (a) design A, (b) design B

The resonators of S1, S2, S3 and S4 are resonated at 24.25, 25.33, 26.42 and 27.5 GHz respectively in K-band. Each resonator is ideally controlled using PIN diodes (D1, D2, D3 and D4). These resonant

frequencies are expected to cover for 5G telecommunication in 26 GHz band [31]. Besides, the design can be used in RF switch circuit as reported in [32]-[34]. Both designs in Figure 3 (a) and 3 (b) has different length of *k*-inverter between the resonators where design A has five times the quarter wavelength (5 λ /4) and design B has three times the quarter wavelength (3 λ /4). Consequently, the total size of design A is 44 × 30 mm while the total size of design B is 33 × 30 mm where the circuit design B is smaller size compared to design A. Design B was selected for verification and thus was fabricated as a prototype as depicted in Figure 4. The prototype is without PIN diodes where it was measured as an ideal PIN diode as same as in the simulation in the CST software. As shown in Figure 4, it is an open circuited for OFF state for allpass response. For bandstop response, a copper tape was used as a short circuited for ON state.



Figure 4. Prototype of design B (dimension: 33×30 mm)

3. RESULTS AND DISCUSSION

3.1. Switchable transmission line SIW resonators with microstrip transition

The simulation results of transition design in Figure 2 (a) and 2 (b) are compared in this section in order to find the best transition. The circuit configuration for both designs were simulated with the length of microstrip transition, $l_{\text{Transition}}=1.95 \text{ mm} (\lambda/4)$, length of the SIW resonator, $l_{\text{SIW}}=4.8 \text{ mm}$ (resonated at 27.5 GHz), the diameter of the via, d=0.75 mm and the pitch between the via, p=1.0 mm. Take note that the simulation was done by using ideal PIN diode as discussion in section 2.

Figure 5 (a) and 5 (b) show the allpass response and Figure 6 (a) and 6 (b) show the bandstop response for both tapered microstrip transition and rectangle microstrip transition. In Figure 5 (a), the return loss (S11) for both transitions achieved more than 10 dB at 27.5 GHz. Meanwhile, the insertion loss (S21) in Figure 5 (b) also produced the same result for both transitions which was less than 0.5 dB at 27.5 GHz.



Figure 5. Allpass response for; (a) return loss, (b) insertion loss of SIW resonator with different microstrip transitions

Figure 6 (a) is the result of return loss (S11) for bandstop response for both circuit designs. The tapered microstrip transition achieved S11 less than 1 dB while the rectangle microstrip transition achieved S11 more than 1 dB at 27.5 GHz. In Figure 6 (b), the maximum attenuation (S21) showed that the tapered microstrip transition and rectangle microstrip transition achieved 27 and 21.5 dB respectively at 27.5 GHz. The SIW resonator with tapered microstrip transition has a slight wider bandwidth of around 2 GHz (at

-3 dB) compared to the rectangle microstrip transition which was 1.7 GHz bandwidth. Table 1 shows the circuit performance comparison for the return loss and insertion loss (of allpass response); and return loss and attenuation (of bandstop response) for the tapered and rectangle microstrip transitions. Therefore, it was found that the switchable SIW resonator with tapered microstrip transition gave a better performance compared to the rectangle microstrip transition. Thus, the next performance analysis of design A and B is based on the tapered microstrip transition.



Figure 6. Bandstop response of; (a) return loss, (b) attenuation of SIW resonator with different microstrip transitions

Tuble 1. Comparison of 51W resonator between uppered and recaugic interostrip transitions					
	Return Loss (Allpass response) @ 27.5 GHZ	Return Loss (Bandstop response) @ 27.5 GHz	Insertion Loss (Allpass response) @ 27.5 GHz	Attenuation (Bandstop response) @ 27.5 GHz	
Tapered microstrip transition	> 10 dB	< 1 dB	< 0.5 dB	27 dB (max)	
Rectangle microstrip transition	> 10 dB	> 1 dB	< 0.5 dB	21.5 dB (max)	

Table 1. Comparison of SIW resonator between tapered and rectangle microstrip transitions

3.2. Cascaded switchable transmission line SIW resonators

After considering the performance analysis of microstrip transition in the filter design, the circuit's design parameters for design A and B are summarized in Table 2. Take note that the simulation performance for design A and B was done by using ideal PIN diode as discussed in section 2.

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	Length of	Length of	Length of	Length of	Width of SIW	Length between	Diameter of	Pitch between
	S1, l_{S1}	S2, l_{S2}	S3, <i>l</i> _{S3}	S4, l_{S4}	resonator, W _{SIW}	SIW resonator, l	the via, d	the via, p
Design A	6.62 mm	5.95 mm	5.35 mm	4.8 mm		9.75 mm (5λ/4)		
	(resonate	(resonate	(resonate	(resonate	5 877 mm		0.75 mm	1.0 mm
Design B	at 24.25	at 25.33	at 26.42	at 27.5	J.022 IIIIII	5.85 mm (3λ/4)	0.75 mm	1.0 11111
	GHz)	GHz)	GHz)	GHz)				

The circuits (design A and B) were simulated in terms of insertion loss (S21 of allpass response), attenuation (S21 of bandstop response) and insertion loss (S11). Figure 7 and 8 show the simulation results of allpass and bandstop responses respectively for design A and B. Figure 7 (a) and 7 (b) are the return loss (S11) and insertion loss (S21) respectively for both circuit designs. The return loss (S11) in Figure 7 (a) during allpass response for design A and design B achieved more than 14.4 dB and 13.9 dB respectively from 24.25 to 27.5 GHz. Meanwhile, in Figure 7 (b), the insertion loss (S21) during allpass response achieved a similar result from 24.25 to 27.5 GHz which was less than 2 dB.



Figure 7. Allpass response of; (a) return loss, (b) insertion loss for design A and B

As shown in Figure 8 (a) and 8 (b), the return loss (S11) and attenuation (S21) for bandstop response of design A and B are plotted and compared. In Figure 8 (a), the return loss (S11) of design A and B achieved the same result which was less than 2.4 dB from 24.25 to 27.5 GHz. As shown in Figure 8 (b), the attenuation performance (from 24.25 to 27.5 GHz) of design A was 10 dB (min) and 37 dB (max); and for design B was 13.3 dB (min) and 40 dB (max). The bandwidth of design B was 4 GHz (at -3 dB) and wider than the bandwidth of design A which was 3.8 GHz (at -3 dB). The comparison between design A and B for the return loss and insertion loss (of allpass response); and return loss and attenuation (of bandstop response) are listed in Table 3.



Figure 8. Bandstop response of; (a) return loss, (b) attenuation for design A and design B

Table 3. Performance comparison between design A and design B				
	Return loss	Return loss	Insertion loss	Attenuation
	(allpass response) @	(bandstop response) @	(allpass response) @	(bandstop response) @
	24.25 – 27.5 GHz	24.25 – 27.5 GHz	24.25 – 27.5 GHz	24.25 – 27.5 GHz
Design A	> 14.4 dB	< 2.4 dB	< 2 dB	10 dB (min)
				37 dB (max)
Design B	> 13.9 dB	< 2.4 dB	< 2 dB	13.3 dB (min)
				40 dB (max)

Figure 9 shows the performance comparison between measurement and simulation results of design B for allpass and bandstop responses. Design B was selected for fabrication since it produced the best performance result of attenuation (S21) and smaller size compared to design A. The measurement was done using a network analyzer to verify with the simulation result. Therefore, Figure 9 (a) shows the comparison of the measurement and simulation of allpass response for return loss and insertion loss. The measured return loss of design B was more than 13.9 dB. On the other hand, the measured insertion loss of design B was less

than 2.2 dB. In Figure 9 (a), the measured result for the insertion loss managed to achieve almost similar with simulated result, while the return loss was noticed that the performance dropped significantly compared to the simulated result. Figure 9 (b) shows the performance comparison of the measurement and simulation results of design B for bandstop response. The measured return loss was less than 9.5 dB. Meanwhile, the measured attenuation for design B was achieving a minimum value of 14.8 dB and maximum value of 39.5 dB (from 24.25 to 27.5 GHz). In Figure 9 (b), the measured attenuation was shifted around 1 GHz and the performance of the return loss was dropped a bit compared to the simulated result. However, in general, it was observed that the measured results were correlated with the simulated results. Table 4 summarized the performance comparison between measurement and simulation results of design B. In future work, the proposed design will be fabricated with actual PIN diode and measured for verification. Then it will be integrated with millimeter wave antennas [35], [36] for any millimetre wave applications.



Figure 9. Measurement versus simulation of design B for, (a) allpass, (b) bandstop responses

Iuc	Table 4. I errormance comparison of measurement and simulation results of design D				
	Return loss	Return loss	Insertion loss	Attenuation	
	(allpass response) @	(bandstop response) @	(allpass response) @	(bandstop response) @	
	24.25-27.5 GHz	24.25-27.5 GHz	24.25-27.5 GHz	24.25-27.5 GHz	
Simulation result	$> 13.9 \mathrm{dB}$	< 2.4 dB	< 2 dB	13.5 dB (min)	
Simulation result	> 15.9 GD	< 2.4 db		39.5 dB (max)	
Measurement	> 13.0 dB	< 9.5 dB	< 2.2 dB	14.8 dB (min)	
result	~ 15.9 UB			39.5 dB (max)	

Table 4. Performance comparison of measurement and simulation results of design B

4. CONCLUSION

The proposed switchable bandstop to allpass filter using cascaded transmission line SIW resonator was succesfully designed and simulated in CST software. It was designed in K-band for millimeter wave application. First, for the analysis of SIW to microstrip line transition, it was found that the switchable SIW resonator with tapered microstrip transition gave a better performance compared to the rectangle microstrip transition. Second, two filter designs with different orientation (design A and B) were investigated for the best performance and compact size. Then, design B was fabricated for measurement and verification with simulated results. As a result, design B is the best by giving a maximum attenuation of 39.5 dB at 26.4 GHz with the layout size of 33×30 mm.

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Switchable bandstop to allpass filter using cascaded transmission line SIW resonators... (A. A. Zolkefli)



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